

# Zn, Ga, and Ca substituted transition-metal-free oxides with $K_2NiF_4$ structures

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Recently, an oxide with  $K_2NiF_4$  structure but free of transition metals was developed with the intent of creating a new solid electrolyte material. Here, the original composition,  $La_{1.6+x}Sr_{0.4-x}Al_{0.4}Mg_{0.6}O_{4+x/2}$ , was modified by replacing Sr, Al, or Mg, with the isovalent substitutes Ca, Ga, or Zn, respectively. The phase stability of these compounds was investigated to determine, specifically, the maximum concentration of oxygen defects allowed by the crystal structure. It was found that a greater concentration of oxygen vacancy defects than interstitials could be created in all of the compositions. In addition, the influence of the cation substitutions on the lattice parameters and the electrical conduction behavior was analyzed. At 650 °C in air, the highest conductivity achieved for B-site substituted compositions was  $2.63 \times 10^{-4} \text{ S cm}^{-1}$  in  $La_{1.5}Sr_{0.5}Al_{0.4}Zn_{0.6}O_{3.9}$ , much higher than  $5.82 \times 10^{-7} \text{ S cm}^{-1}$  in  $La_{1.65}Sr_{0.35}Al_{0.4}Mg_{0.6}O_{4.025}$ , while the highest value for A-site substituted compositions was only  $7.55 \times 10^{-7} \text{ S cm}^{-1}$  in  $La_{1.65}Ca_{0.35}Al_{0.4}Mg_{0.6}O_{4.025}$ . The electrochemical results indicated that A-site substituted compositions, although with low conductivity, were possible oxygen ion conductors, while B-site substituted compositions exhibited either mixed ionic and hole conductivity or pure hole conductivity.

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## 1. Introduction

Solid oxide fuel cells (SOFCs) are a promising alternative power generation source with an electrolyte that is a ceramic conductor of oxygen ions. Compared to proton exchange membrane fuel cells (PEMFCs) and alkaline fuel cells (AFCs), which are typically limited in the choice of operational fuel, SOFCs can make use of a wide variety of fuels including hydrogen, hydrocarbons, alcohols, and other alternatives.<sup>1,2</sup> In order to achieve sufficiently high electrolyte conductivity, SOFCs are usually operated at temperatures of 800 °C or above, which causes a number of issues including delicate gas sealing,<sup>3</sup> material degradation,<sup>4,5</sup> and slow start-up and shut-down. Therefore, new electrolytes with larger oxygen ion conductivity are required to reduce the operating temperature. Materials with the cubic fluorite crystal structure, such as doped zirconia and ceria, are the conventional electrolyte materials for SOFCs.<sup>6–9</sup> More recently, (La, Sr)(Ga, Mg)O<sub>3–δ</sub> (LSGM) with a perovskite structure has been developed as a solid electrolyte with high ionic conductivity,<sup>10–13</sup> and materials with more exotic crystal structures are being actively explored too.<sup>14–17</sup>

$K_2NiF_4$ -type materials, which consist of alternatively stacked perovskite (P-layer) and rocksalt (R-layer) layers, have attracted

attention due to their high oxygen ion conductivity based on an interstitial mechanism.<sup>18–20</sup> Most of the known  $K_2NiF_4$ -type materials have transition-metal elements on the B-site and consequently are mixed ionic electronic conductors (MIEC).<sup>20–23</sup> This prevents their application as solid electrolytes. In our previous work,<sup>24</sup> transition-metal-free  $K_2NiF_4$  structure materials with the composition  $La_{1.6}Sr_{0.4}Al_{0.4}Mg_{0.6}O_4$  (LSAM) were synthesized and shown to have significantly reduced the electron conductivity.

Ionic defects were created in  $La_{1.6+x}Sr_{0.4-x}Al_{0.4}Mg_{0.6}O_{4+x/2}$  compositions by adjusting the La/Sr ratio on the A-site. The stability of the crystal structure to significant defect concentrations can be compared to that of  $LaSrAlO_4$ ,<sup>25</sup> where second phases are found for any composition with La/Sr  $\neq$  1. Based on this result, we proposed that anion defects are stabilized in the  $K_2NiF_4$  structure by Coulombic attraction between the defect and the layer of the crystal structure in which the defect resides: vacancies in the positively charged P-layer and interstitials in the negatively charged R-layer. Thus, a high charge separation between the P-layer with the nominal composition  $ABO_3$  and R-layer with the nominal composition  $AO$  is desired. In  $LaSrAlO_4$ , the P-layer consists of  $(La_{0.5}Sr_{0.5}AlO_3)^{-0.5}$  while the R-layer consists of  $(La_{0.5}Sr_{0.5}O)^{+0.5}$ . In comparison, the prototypical composition  $La_2NiO_4$ , which supports large anion defect concentrations, consists of a  $(LaNiO_3)^{-1}$  P-layer and a  $(LaO)^{+1}$  R-layer (neglecting partial oxidation of the Ni).  $La_{1.6}Sr_{0.4}Al_{0.4}Mg_{0.6}O_4$  was found in our previous work to provide maximal charge separation in the  $La_{2-x}Sr_xAl_xMg_{1-x}O_4$  composition space while maintaining the  $K_2NiF_4$  crystal structure,

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with nominal P-layer and R-layer charges of  $-0.8$  and  $+0.8$ , respectively.

In this paper, Ca, Ga, or Zn substitute for Sr, Al, or Mg, respectively, in LSAM and the effects of these substitutions on the phase stability and conductivity are studied. Ca substitution is chosen because its smaller ionic radius is known to increase the concentration of oxygen interstitials in  $\text{La}_2\text{NiO}_4$ .<sup>26</sup> Ga is selected to replace Al based on the previous success of high oxygen ion conductivity in the related perovskite LSGM. Zn is examined in the interest of increasing the cell volume to promote ion mobility.<sup>27,28</sup> Of specific interest is whether these substitutions are able to increase oxygen defect mobility and/or increase available defect concentrations by allowing increased P-layer/R-layer charge separation with nominal compositions beyond  $(\text{A}^{3+}_{1.6}\text{A}^{2+}_{0.4})(\text{B}^{3+}_{0.4}\text{B}^{2+}_{0.6})\text{O}_4$ .

## 2. Experiments

### 2.1 Synthesis and structural characterization

The samples were all prepared by solid state reactions. Reagents of  $\text{La}_2\text{O}_3$  (99.999%, Inframat Advanced Materials),  $\text{SrCO}_3$  (99.5+%, Inframat Advanced Materials),  $\text{Mg}(\text{OH})_2$  (98.4%, Alfa Aesar),  $\text{Al}_2\text{O}_3$  (99.5% metal basis, Alfa Aesar),  $\text{Ga}_2\text{O}_3$  (99.99% metal basis, Alfa Aesar),  $\text{ZnO}$  (99.9% metal basis, Alfa Aesar) and  $\text{CaCO}_3$  (99.5% metal basis, Alfa Aesar) were used as the starting raw materials. These reagents were weighed stoichiometrically and then ball milled using spherical YSZ milling media for 20 hours in deionized water. The grinding media were removed from the mixed reagents and then rinsed with DI water for 5 min in an ultrasonic bath 5 times, after which the rinse water was visually clean. All of the rinsed water was collected and heated with the milled dispersion on a hotplate to reduce the loss of chemicals. Finally, the dried precursors were milled in an agate mortar and calcined at  $1350^\circ\text{C}$  for 5 hours with equal heating and cooling rates of  $100^\circ\text{C h}^{-1}$ . The as-synthesized materials were structurally characterized in conventional  $\theta$ - $2\theta$  geometry on a PANalytical X'Pert X-ray diffractometer (XRD) using  $\text{Cu-K}\alpha$  radiation. The lattice parameters were determined from XRD patterns using Jade software (ver. 5.0, Materials Data, Inc.). Calcined powders were uniaxially pressed without a binder at a pressure of 300 MPa and then sintered at  $1450^\circ\text{C}$  for 10 h with an equal heating and cooling rate of  $100^\circ\text{C h}^{-1}$  to obtain pellets with density  $>95\%$ . The microstructures of the sintered pellets were characterized by scanning electron microscopy (SEM, JOEL JSM-7400F) with a 3 keV accelerating voltage. Imaged surfaces were polished to 800-grit, thermally etched in air at  $1150^\circ\text{C}$  for 6 h, and then coated with roughly 10 nm of gold-palladium (60% Au, 40% Pd).

### 2.2 Conductivity measurement

The sintered pellets were polished by hand into a rectangular shape with dimensions  $12\text{ mm} \times 5\text{ mm} \times 1\text{ mm}$ . Four silver paint electrodes were applied along the length of the sample for four-probe DC conductivity measurements. Electrical measurements were collected using a Keithley 2601A Source-meter with linear sweep voltages between  $-1\text{ V}$  and  $+1\text{ V}$ . This

relatively wide voltage range was used to reduce the noise in the current signal despite high sample resistances. The linearity of the current-voltage relationship over the entire range suggested that no oxidation or reduction of the materials under test occurred. The temperature was controlled between  $300^\circ\text{C}$  and  $650^\circ\text{C}$  in a tube furnace and directly measured with a thermocouple in close proximity to the sample. Flowing dry air and commercial  $\text{Ar-O}_2$  mixtures were used to change the oxygen partial pressure.

## 3. Results and discussions

Starting from a composition of  $\text{La}_{1.6}\text{Sr}_{0.4}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_4$ , efforts were made to increase the P-layer/R-layer charge separation when substituting Ga, Zn, or Ca. As seen in Fig. 1, the direct substitution for Al, Mg, and Ca maintained the  $\text{K}_2\text{NiF}_4$  crystal structures; however, for all three substitutions, the charge separation could not increase from  $-0.8/+0.8$  to  $-0.85/+0.85$  by changing the nominal composition from  $(\text{A}^{3+}_{1.6}\text{A}^{2+}_{0.4})(\text{B}^{3+}_{0.4}\text{B}^{2+}_{0.6})\text{O}_4$  to  $(\text{A}^{3+}_{1.7}\text{A}^{2+}_{0.3})(\text{B}^{3+}_{0.3}\text{B}^{2+}_{0.7})\text{O}_4$ . Increasing the charge separation in all cases led to the appearance of second phase  $\text{La}_2\text{O}_3$ .

By comparing the XRD results of the samples with the nominal composition  $(\text{A}^{3+}_{1.6}\text{A}^{2+}_{0.4})(\text{B}^{3+}_{0.4}\text{B}^{2+}_{0.6})\text{O}_4$  in Fig. 1, the peak locations of the Ca substituted sample are clearly shifted to a higher angle compared to the corresponding peaks of the Ga or Zn containing samples, indicating reduced lattice parameters. Lattice parameters for these and other compositions as determined from the XRD patterns are given in Table 1. The table shows that both  $a$  and  $c$  lattice parameters of LSAM are increased by Ga and Zn substitution, while they are both reduced by Ca substitution. These results are intuitive, since the ionic radii of Ga and Zn are larger than those of Al and Mg, but the ionic radius of Ca is smaller than that of Sr.

As shown in Fig. 2, the microstructures of the sintered pellets reveal that dense ceramic structures with little porosity are obtained for all three stoichiometric samples. This result is consistent with the  $>95\%$  pellet densities determined by Archimedes' method. The grain sizes for the sintered pellets are between  $1\text{ }\mu\text{m}$  and  $8\text{ }\mu\text{m}$ . No intergranular phases are observed

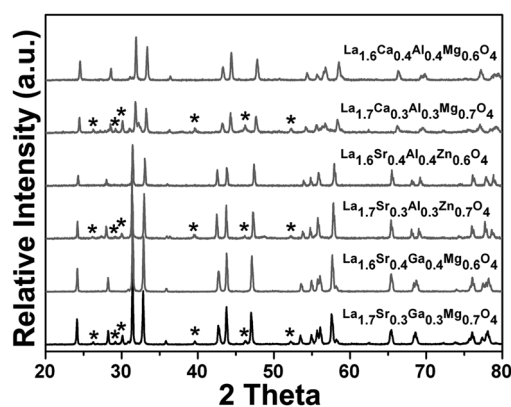


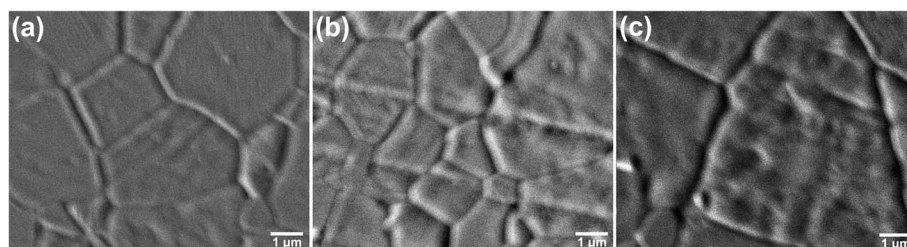
Fig. 1 XRD patterns of Ga, Zn, and Ca substituted samples. Peaks marked by \* indicate the secondary phase of  $\text{La}_2\text{O}_3$ .



**Table 1** Calculated lattice parameters and the ratio of the average ionic radii for all samples studied in this work. Lattice parameters written in boldface indicate phase pure samples; otherwise the parameters given indicate those of the  $K_2NiF_4$  phase within the mixture

Nominal composition		Cation radius ratio <sup>a</sup>		K <sub>2</sub> NiF <sub>4</sub> phase lattice parameter (Å)	
		$r_A(IX)/r_B(VI)$	Phase	<i>a</i>	<i>c</i>
Ca substitution	La <sub>2</sub> NiO <sub>4</sub> <sup>b</sup>	1.76	K <sub>2</sub> NiF <sub>4</sub>	<b>3.861</b>	<b>12.68</b>
	La <sub>1.6</sub> Sr <sub>0.4</sub> Al <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>4</sub> (ref. 24)	1.91	K <sub>2</sub> NiF <sub>4</sub>	<b>3.829</b>	<b>12.646</b>
	La <sub>1.7</sub> Ca <sub>0.3</sub> Al <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>4.05</sub>	1.87	K <sub>2</sub> NiF <sub>4</sub> , La <sub>2</sub> O <sub>3</sub>	3.818	12.490
	La <sub>1.65</sub> Ca <sub>0.35</sub> Al <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>4.025</sub>	1.87	K <sub>2</sub> NiF <sub>4</sub>	<b>3.820</b>	<b>12.548</b>
	La <sub>1.6</sub> Ca <sub>0.4</sub> Al <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>4</sub>	1.87	K <sub>2</sub> NiF <sub>4</sub>	<b>3.804</b>	<b>12.530</b>
	La <sub>1.5</sub> Ca <sub>0.5</sub> Al <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>3.95</sub>	1.87	K <sub>2</sub> NiF <sub>4</sub>	<b>3.803</b>	<b>12.512</b>
	La <sub>1.4</sub> Ca <sub>0.6</sub> Al <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>3.9</sub>	1.87	K <sub>2</sub> NiF <sub>4</sub>	<b>3.800</b>	<b>12.507</b>
	La <sub>1.3</sub> Ca <sub>0.7</sub> Al <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>3.85</sub>	1.86	K <sub>2</sub> NiF <sub>4</sub> , CaO	3.798	12.514
Ga substitution	La <sub>1.7</sub> Ca <sub>0.3</sub> Al <sub>0.3</sub> Mg <sub>0.7</sub> O <sub>4</sub>	1.82	K <sub>2</sub> NiF <sub>4</sub> , La <sub>2</sub> O <sub>3</sub>	3.819	12.538
	La <sub>1.5</sub> Ca <sub>0.5</sub> Al <sub>0.5</sub> Mg <sub>0.5</sub> O <sub>4</sub>	1.92	K <sub>2</sub> NiF <sub>4</sub> , Al <sub>2</sub> Ca <sub>3</sub> O <sub>6</sub>	3.792	12.508
	La <sub>1.7</sub> Sr <sub>0.3</sub> Ga <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>4.05</sub>	1.81	K <sub>2</sub> NiF <sub>4</sub>	3.866	12.677
			La <sub>4</sub> Ga <sub>2</sub> O <sub>9</sub>		
	La <sub>1.6</sub> Sr <sub>0.4</sub> Ga <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>4</sub>	1.82	K <sub>2</sub> NiF <sub>4</sub>	<b>3.861</b>	<b>12.681</b>
	La <sub>1.5</sub> Sr <sub>0.5</sub> Ga <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>3.95</sub>	1.82	K <sub>2</sub> NiF <sub>4</sub>	<b>3.862</b>	<b>12.689</b>
	La <sub>1.4</sub> Sr <sub>0.6</sub> Ga <sub>0.4</sub> Mg <sub>0.6</sub> O <sub>3.9</sub>	1.83	K <sub>2</sub> NiF <sub>4</sub>	3.862	12.684
			LaSr <sub>2</sub> GaO <sub>5</sub>		
Zn substitution	La <sub>1.7</sub> Sr <sub>0.3</sub> Ga <sub>0.3</sub> Mg <sub>0.7</sub> O <sub>4</sub>	1.78	K <sub>2</sub> NiF <sub>4</sub> , La <sub>2</sub> O <sub>3</sub>	3.866	12.670
	La <sub>1.7</sub> Sr <sub>0.3</sub> Al <sub>0.4</sub> Zn <sub>0.6</sub> O <sub>4.05</sub>	1.87	K <sub>2</sub> NiF <sub>4</sub> , La <sub>2</sub> O <sub>3</sub>	3.832	12.723
			LaAlO <sub>3</sub>		
	La <sub>1.65</sub> Sr <sub>0.35</sub> Al <sub>0.4</sub> Zn <sub>0.6</sub> O <sub>4.025</sub>	1.87	K <sub>2</sub> NiF <sub>4</sub>	<b>3.836</b>	<b>12.741</b>
	La <sub>1.6</sub> Sr <sub>0.4</sub> Al <sub>0.4</sub> Zn <sub>0.6</sub> O <sub>4</sub>	1.88	K <sub>2</sub> NiF <sub>4</sub>	<b>3.831</b>	<b>12.762</b>
	La <sub>1.55</sub> Sr <sub>0.45</sub> Al <sub>0.4</sub> Zn <sub>0.6</sub> O <sub>3.975</sub>	1.88	K <sub>2</sub> NiF <sub>4</sub>	<b>3.835</b>	<b>12.757</b>
	La <sub>1.5</sub> Sr <sub>0.5</sub> Al <sub>0.4</sub> Zn <sub>0.6</sub> O <sub>3.95</sub>	1.88	K <sub>2</sub> NiF <sub>4</sub>	<b>3.827</b>	<b>12.785</b>
	La <sub>1.4</sub> Sr <sub>0.6</sub> Al <sub>0.4</sub> Zn <sub>0.6</sub> O <sub>3.9</sub>	1.89	K <sub>2</sub> NiF <sub>4</sub>	<b>3.815</b>	<b>12.832</b>
	La <sub>1.3</sub> Sr <sub>0.7</sub> Al <sub>0.4</sub> Zn <sub>0.6</sub> O <sub>3.85</sub>	1.90	K <sub>2</sub> NiF <sub>4</sub> , La <sub>2</sub> O <sub>3</sub>	3.807	12.909
	La <sub>1.7</sub> Sr <sub>0.3</sub> Al <sub>0.3</sub> Zn <sub>0.7</sub> O <sub>4</sub>	1.81	K <sub>2</sub> NiF <sub>4</sub> , La <sub>2</sub> O <sub>3</sub>	3.844	12.759
	La <sub>1.5</sub> Sr <sub>0.5</sub> Al <sub>0.5</sub> Zn <sub>0.5</sub> O <sub>4</sub>	1.94	K <sub>2</sub> NiF <sub>4</sub> , La <sub>2</sub> O <sub>3</sub>	3.821	12.743

<sup>a</sup> The ionic radii are from R. D. Shannon.<sup>29</sup>  $r_{(La^{3+},IX)} = 1.216$  Å;  $r_{(Ni^{2+},VI)} = 0.69$  Å;  $r_{(Sr^{2+},IX)} = 1.31$  Å;  $r_{(Al^{3+},VI)} = 0.535$  Å;  $r_{(Mg^{2+},VI)} = 0.72$  Å;  $r_{(Ca^{2+},IX)} = 1.18$  Å;  $r_{(Ga^{3+},VI)} = 0.62$  Å;  $r_{(Zn^{2+},VI)} = 0.74$  Å. <sup>b</sup> Lattice parameters of La<sub>2</sub>NiO<sub>4</sub> are from JCPDS card 34-0314.



**Fig. 2** Representative SEM micrographs of the polished and thermally etched surfaces of sintered pellets with compositions (a) La<sub>1.6</sub>Ca<sub>0.4</sub>Al<sub>0.4</sub>Mg<sub>0.6</sub>O<sub>4</sub>, (b) La<sub>1.6</sub>Sr<sub>0.4</sub>Ga<sub>0.4</sub>Mg<sub>0.6</sub>O<sub>4</sub>, and (c) La<sub>1.6</sub>Sr<sub>0.4</sub>Al<sub>0.4</sub>Zn<sub>0.6</sub>O<sub>4</sub>.

in the micrographs, though they may be present at quantities/thicknesses smaller than could be observed presently.

Fig. 3 shows the results of adjusting the A-site ratio in order to create ionic defects. Increasing the ratio of  $A^{3+}/A^{2+}$  ( $x > 0$ ) in  $(A^{3+}_{1.6+x}A^{2+}_{0.4-x})(B^{3+}_{0.4}B^{2+}_{0.6})O_{4+x/2}$  ideally creates oxygen interstitials, while decreasing the ratio ( $x < 0$ ) creates oxygen vacancies. The XRD results in Fig. 3 indicate that, for all samples studied, a higher concentration of oxygen vacancies could be created relative to oxygen interstitials before the appearance of secondary phases. In Ga containing samples,  $x$  could be  $-0.1$  without second phases, whereas La<sub>4</sub>Ga<sub>2</sub>O<sub>9</sub> peaks

appear when  $x = +0.1$ . For both Zn and Ca substitutions, the K<sub>2</sub>NiF<sub>4</sub> structure was stable when  $-0.2 \leq x \leq +0.05$ . In the Zn containing specimen, increasing amounts of oxygen vacancies lead to reduction in the  $a$  lattice parameter and increase in the  $c$  parameter. This leads to increased peak splitting between the (133) and (008) peaks. Thus, the peak at  $2\theta = 57.41^\circ$  marked with  $\odot$  for the  $x = -0.2$  sample in Fig. 3(b) is the (008) peak of the K<sub>2</sub>NiF<sub>4</sub> structure. Since the ionic radii of the A-site cations are  $r_{(Sr^{2+},IX)} = 1.31$  Å  $>$   $r_{(La^{3+},IX)} = 1.216$  Å  $>$   $r_{(Ca^{2+},IX)} = 1.18$  Å, reducing the La/Sr ratio in Zn containing samples caused a significant increase of the lattice parameter  $c$ , while reducing



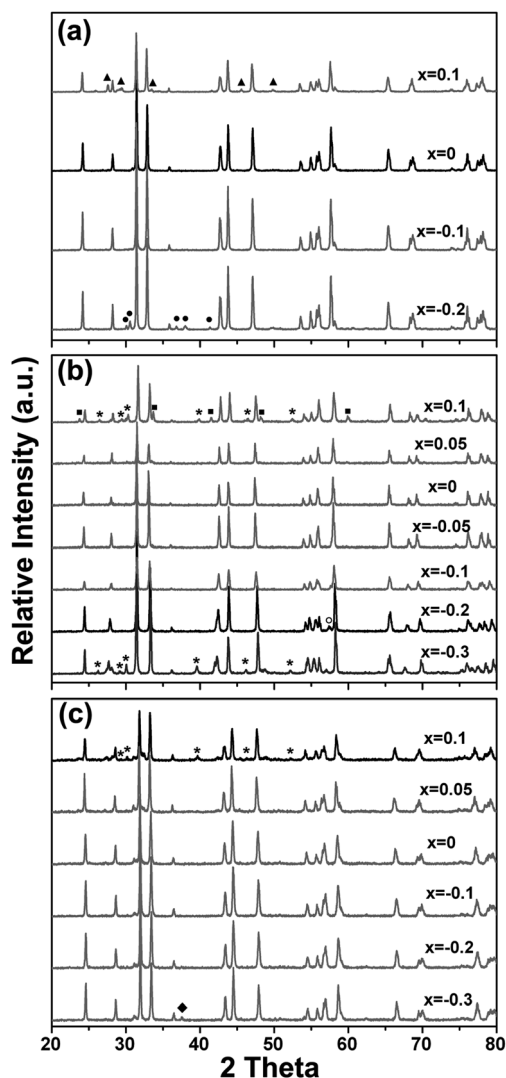


Fig. 3 (a) XRD patterns of  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$ ; (b) XRD patterns of  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{4+x/2}$ ; (c) XRD patterns of  $\text{La}_{1.6+x}\text{Ca}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$ . Peaks marked by \* indicate  $\text{La}_2\text{O}_3$ , ▲ indicate  $\text{La}_4\text{Ga}_2\text{O}_9$ , ● indicate  $\text{LaSr}_2\text{GaO}_5$ , ■ indicate  $\text{LaAlO}_3$ , and ◆ indicate  $\text{CaO}$ .

the La/Ca ratio in Ca containing samples led to a significant decrease of the lattice parameter  $c$ . In general, reducing the La/Sr or La/Ca ratio caused a slight decrease in the lattice parameter  $a$ .

Table 1 gives the calculated lattice parameters based on XRD alongside the ratio of the ionic radii of the A-site cation to that of the B-site cation. Since multiple cations are present on each site, weighted average ionic radii are used, taking the radii in a 9-fold coordination for the A-site and a 6-fold coordination for the B-site. Ganguli suggested that the ratio of ionic radii,  $r_{\text{A}}(\text{IX})/r_{\text{B}}(\text{VI})$ , should be between about 1.7 and 2.4 in order to retain the  $\text{K}_2\text{NiF}_4$  phase.<sup>30</sup> As indicated by the results in Table 1, all compositions in this study, even those with multiple phases present, satisfy the rule.

The substitution of Ca on the A-site caused relatively little change in the total electrical conductivity. As shown in Fig. 4,

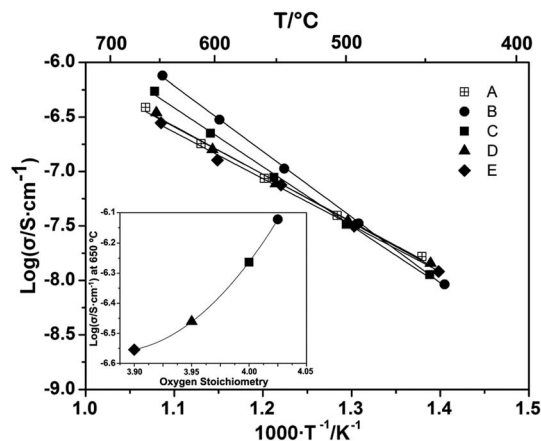


Fig. 4 Arrhenius plot of total electrical conductivity measured in air for (A)  $\text{La}_{1.6}\text{Sr}_{0.4}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4.24}$  and the Ca substituted samples (B)  $\text{La}_{1.65}\text{Ca}_{0.35}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4.025}$ ; (C)  $\text{La}_{1.6}\text{Ca}_{0.4}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_4$ ; (D)  $\text{La}_{1.5}\text{Ca}_{0.5}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{3.95}$ ; (E)  $\text{La}_{1.4}\text{Ca}_{0.6}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{3.9}$ . The inset figure displays the conductivity at 650 °C vs. the oxygen stoichiometry.

increasing the La/Ca ratio in order to create oxygen interstitials caused an increase in both the high temperature conductivity and activation energy of conduction. The electrical conductivity of  $\text{La}_{1.6+x}\text{Ca}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_4$  is very similar to the previously reported values for  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4.24}$ . The inset in Fig. 4 plots the conductivity at 650 °C vs. the oxygen stoichiometry and suggests a moderate amount of interstitial conductivity in both the superstoichiometric and stoichiometric compositions. When the La/Ca ratio is reduced such that vacancies are expected on the oxygen sublattice, the conductivity values are within the experimental error of that of the previously reported  $\text{La}_{1.6}\text{Sr}_{0.4}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_4$  sample. These results indicate that the vacancies have low mobility. The similarity of the conductivity values for these samples, despite the increasing vacancy concentration, suggests that the charge carrier concentration does not change with the composition. The

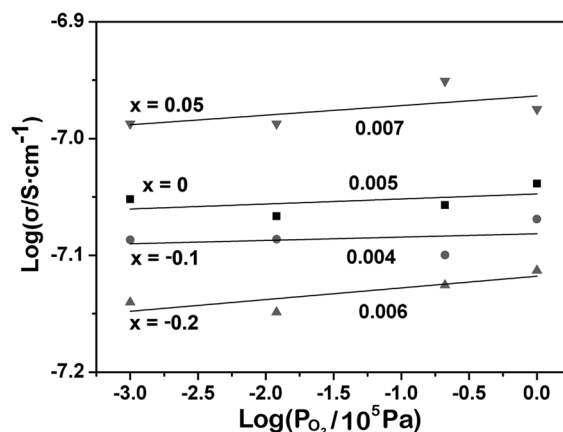


Fig. 5 Total electrical conductivity at 550 °C of  $\text{La}_{1.6+x}\text{Ca}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$  vs. oxygen partial pressure for compositions with  $x = -0.2, -0.1, 0$ , and  $+0.05$ . The near-zero slopes of the best fit lines are indicated next to each line.



carrier concentration is thus determined by either intrinsic defects or impurities acting as dopants.

Fig. 5 shows the conductivity of the  $\text{La}_{1.6+x}\text{Ca}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$  samples at 550 °C over a range of oxygen partial pressures. The conductivities of all compositions are essentially independent of the oxygen partial pressure, with the slopes of the best-fit lines  $\leq 0.007$ . This result gives further indication that the dominant charge carriers are ionic,<sup>31–34</sup> since electronic carriers are expected to have concentrations that are determined by oxidation reactions and are thus dependent upon the oxygen partial pressure.<sup>34–37</sup> Nevertheless, the small change in conductivity despite  $x$  varying between +0.05 and –0.2 implies a low mobility of the created defects. A similar phenomenon was observed in  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$ ,<sup>24</sup> which has the same B-site composition. The reason that defect mobilities are low in  $\text{K}_2\text{NiF}_4$  materials that have only period 3 elements in the B-site remains an open question, but is perhaps due to the small cell volume<sup>27,28</sup> and/or low polarizability<sup>38</sup> related to their small ionic radii.

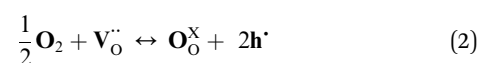
Fig. 6 shows that B-site substitutions caused a much greater change in conductivity than A-site substitutions. For the oxygen stoichiometric compositions, Ga substitution yielded roughly one order of magnitude increase in the electrical conductivity relative to the original LSAM composition, and Zn substitution caused a further increase by a little over one order of magnitude. Unlike the LSAM or the Ca-substituted compositions, decreasing the La/Sr ratio from that of the stoichiometric composition in the Ga- and Zn-substituted samples increased the conductivity. In the Zn-containing compositions, the conductivity improves from  $x = 0$  to  $x = -0.1$ , however, further increases in the defect concentration at  $x = -0.2$  yields lower conductivity. The reason for this may be an impurity phase not perceptible by XRD or SEM. A strong possibility is a Sr-rich phase, which is often observed to form a poorly-conducting

layer at grain boundaries in perovskite oxide ion conductors.<sup>39,40</sup> An increase in activation energy from 1.15 eV for  $x = -0.1$  to 1.30 eV for  $x = -0.2$  could be seen as evidence for this hypothesis, but confirmation is still needed. Increasing the La/Sr ratio from that of the stoichiometric composition in the Zn-substituted samples (which was not possible in the Ga-substituted samples) reduced the conductivity significantly.

Fig. 7 shows the total electrical conductivity at 550 °C of  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$  measured in various oxygen partial pressures. The electrical conductivity of stoichiometric  $\text{La}_{1.6}\text{Sr}_{0.4}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_4$  has near-zero dependence on the oxygen partial pressure, indicating that the conduction mechanism is *via* intrinsic defects at a concentration larger than that created by redox reactions. Studies of the similar compositions  $\text{LaSrGa}_{1-x}\text{Mg}_x\text{O}_{4-x/2}$  (for which a low value of 0.03 was reported as the maximum possible  $x$ , consistent with our theory of defects being stabilized by charge separation between the P-layer and R-layer), found evidence of oxygen ion conduction,<sup>41</sup> but ionic conduction cannot be definitively determined here. Oxygen substoichiometric  $\text{La}_{1.5}\text{Sr}_{0.5}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{3.95}$  exhibited a more clear oxygen partial pressure dependence of conductivity. The total conductivity can be represented by:<sup>34–37</sup>

$$\sigma_{\text{tot}} = \sigma_{\text{ion}} + \sigma_{\text{h}}^0 P_{\text{O}_2}^{1/4} \quad (1)$$

where  $\sigma_{\text{tot}}$  is the total conductivity,  $\sigma_{\text{ion}}$  is the oxygen ionic conductivity and  $\sigma_{\text{h}}^0$  is the hole conductivity at  $P_{\text{O}_2} = 1$  atm. Eqn (1) indicates that oxygen ion conductivity is independent of oxygen partial pressure while the hole conductivity has a 1/4 power law dependence. This power law can be derived from the oxidation reaction:



in which  $\text{V}_{\text{O}}^{\bullet\bullet}$  is a vacant oxygen site,  $\text{O}_{\text{O}}^{\times}$  is an occupied oxygen site, and  $\text{h}^{\bullet}$  is a hole. With the concentration of oxygen vacancies held approximately constant by the stoichiometry, the mass action law of reaction (2) provides a 1/4 power law dependence

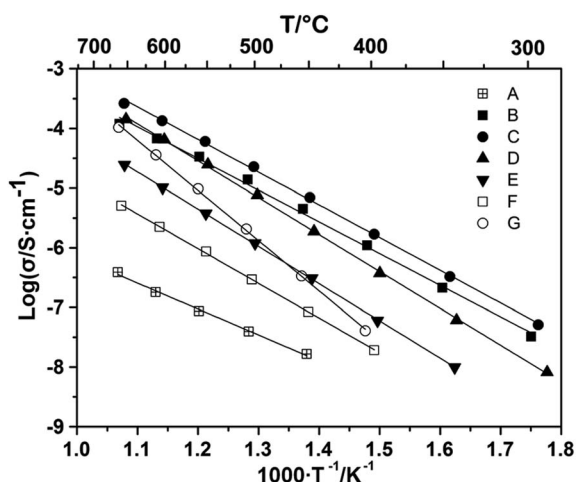


Fig. 6 Arrhenius plot of the total electrical conductivity measured in air for (A)  $\text{La}_{1.6}\text{Sr}_{0.4}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_4$ ;<sup>24</sup> and the B-site substituted samples (B)  $\text{La}_{1.6}\text{Sr}_{0.4}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_4$ ; (C)  $\text{La}_{1.5}\text{Sr}_{0.5}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{3.95}$ ; (D)  $\text{La}_{1.4}\text{Sr}_{0.6}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{3.9}$ ; (E)  $\text{La}_{1.65}\text{Sr}_{0.35}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{4.025}$ ; (F)  $\text{La}_{1.6}\text{Sr}_{0.4}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_4$ ; (G)  $\text{La}_{1.5}\text{Sr}_{0.5}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{3.95}$ . In all cases, square symbols indicate compositions with stoichiometric oxygen content.

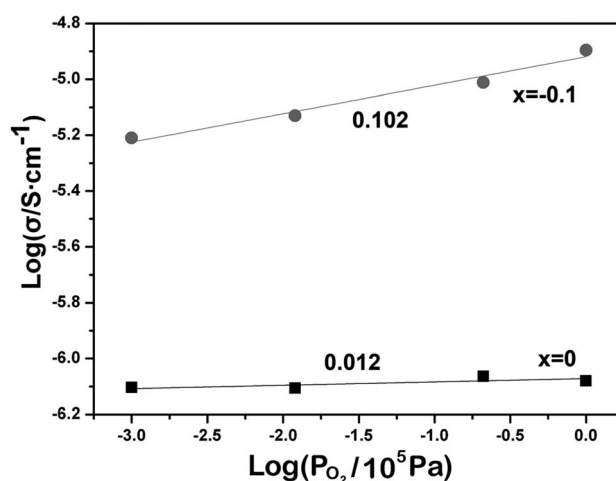


Fig. 7 Total electrical conductivity at 550 °C of  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$  vs. oxygen partial pressure for compositions with  $x = -0.1$  and 0. The slopes of the best-fit lines are indicated.



of the hole concentration.<sup>34–37,42</sup> The oxygen partial pressure dependence of conductivity measured for  $\text{La}_{1.5}\text{Sr}_{0.5}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{3.95}$  is about 0.102. The deviation from the classic 1/4 power dependence is very common in other mixed conducting materials.<sup>43,44</sup> Since the conductivity increases with oxygen substoichiometry, the predominant charge carrier in  $\text{La}_{1.5}\text{Sr}_{0.5}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{3.95}$  seems to be mixed between vacancies and holes.

Fig. 8 shows the total electrical conductivity at 550 °C of the  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{4+x/2}$  series samples over a range of oxygen partial pressures. When  $x$  is between 0 and  $-0.2$ , the conductivity has a roughly 1/4 power law dependence over the entire range of oxygen partial pressures. This result indicates that the main charge carriers are holes, as described previously. For the  $x = +0.05$  composition, where interstitial defects are expected, the slope of the oxygen partial pressure dependence appears to be 1/6. This result suggests that the defect concentration is no longer fixed by the stoichiometry, but rather the charge carrier concentrations are determined by the oxidation reaction.<sup>42</sup>

In this work, A-site and B-site substitutions caused contrasting effects on the conductivity. While all of the tested compositional changes caused increases in the conductivity of stoichiometric samples, the A-site substitution of Ca caused the conductivity to increase with increasing interstitial defects and decrease with vacancy defects. In contrast, both B-site substitutions caused the conductivity to increase with the presence of vacancies and decrease with interstitial defects—if the crystal structure even allowed them. This result further supports the notion that positively charged vacancies prefer to inhabit a negatively charged perovskite layer with the composition  $\text{ABO}_3$  and negatively charged interstitials prefer to inhabit a positively charged rocksalt layer with the composition  $\text{AO}$ . Still, the presence of mixed conduction in the B-site substituted samples indicates that getting sufficient oxide ion mobility without coincident electron/hole conductivity in the  $\text{K}_2\text{NiF}_4$  structure will be difficult.

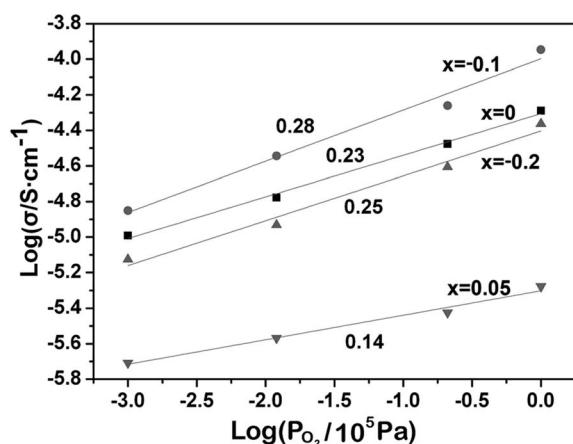


Fig. 8 Total electrical conductivity at 550 °C of  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{4+x/2}$  vs. oxygen partial pressure for compositions with  $x = -0.2, -0.1, 0$ , and  $+0.05$ . The slopes of the best fit lines are indicated.

In the transition-metal-free  $\text{K}_2\text{NiF}_4$  oxides, the electronic conductivity could be greatly suppressed compared to prototype  $\text{La}_2\text{NiO}_4$  materials. Large amounts of oxygen defects could also be created. Nonetheless, probably due to the presence of alkaline earth metal/post-transition metals in the B-site, the as-created oxygen defects had low mobility. Therefore, although oxygen ion conductors were achieved with A-site substitution of Ca, the ionic conductivity remained extremely low. In future work, a new strategy to select B-site atoms that increase the mobility of oxygen defects without reintroducing electronic conductivity would be key to the success of designing  $\text{K}_2\text{NiF}_4$  electrolyte materials.

## 4. Conclusions

$\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$  ( $-0.1 \leq x \leq 0$ ),  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{4+x/2}$  ( $-0.2 \leq x \leq +0.05$ ) and  $\text{La}_{1.6+x}\text{Ca}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$  ( $-0.2 \leq x \leq +0.05$ ) with  $\text{K}_2\text{NiF}_4$  structures were synthesized without impurity phases. Compared to the electrical conductivity of LSAM, the electrical conductivity was relatively constant when replacing Sr with Ca, but increased between 1 and 2.5 orders of magnitude when substituting Al or Mg with Ga or Zn. Electrochemical analysis revealed that  $\text{La}_{1.6+x}\text{Ca}_{0.4-x}\text{Al}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$  appeared to support the electrolytic conduction of interstitial oxygen ions, though with low conductivity. Conversely, the main carriers in  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Al}_{0.4}\text{Zn}_{0.6}\text{O}_{4+x/2}$  seemed to be holes. In  $\text{La}_{1.6+x}\text{Sr}_{0.4-x}\text{Ga}_{0.4}\text{Mg}_{0.6}\text{O}_{4+x/2}$ ,  $x = 0$  appeared to be predominantly an ionic conductor while  $x = -0.1$  was a mixed conductor of holes and oxygen vacancies. The results indicate that electrolytic conduction is possible in transition-metal-free  $\text{K}_2\text{NiF}_4$  oxides, but high ionic mobility is yet to be achieved.

## References

- 1 B. C. H. Steele and A. Heinzl, *Nature*, 2001, **414**, 345–352.
- 2 E. D. Wachsman, *Science*, 2011, **334**, 935–939.
- 3 R. N. Singh, *J. Mater. Eng. Perform.*, 2006, **15**, 422–426.
- 4 N. Sakai, T. Horita, K. Yamaji, Y. Xiong, H. Kishimoto, M. Brito and H. Yokokawa, *Solid State Ionics*, 2006, **177**, 1933–1939.
- 5 Z. Yang, M. S. Walker, P. Singh and J. W. Stevenson, *Electrochem. Solid-State Lett.*, 2003, **6**, B35–B37.
- 6 H. L. Tuller, *Solid State Ionics*, 2000, **131**, 143–157.
- 7 C. S. Tedmon, H. S. Spacil and S. P. Mitoff, *J. Electrochem. Soc.*, 1969, **116**, 1170–1175.
- 8 J. L. Hertz and H. L. Tuller, *J. Electrochem. Soc.*, 2007, **154**, B413–B418.
- 9 H. L. Tuller and A. S. Nowick, *J. Electrochem. Soc.*, 1975, **122**, 255–259.
- 10 T. Ishihara, H. Matsuda and Y. Takita, *J. Am. Chem. Soc.*, 1994, **116**, 3801–3803.
- 11 S. Tao, F. W. Poulsen, G. Meng and O. T. Sørensen, *J. Mater. Chem.*, 2000, **10**, 1829–1833.
- 12 C. N. Munnings, S. J. Skinner, G. Amow, P. S. Whitfield and I. J. Davidson, *J. Fuel Cell Sci. Technol.*, 2005, **2**, 34–37.



- 13 M. Li, Y. Zhang, M. An, Z. Lü, X. Huang, J. Xiao, B. Wei, X. Zhu and W. Su, *J. Power Sources*, 2012, **218**, 233–236.
- 14 X. Kuang, M. A. Green, H. Niu, P. Zajdel, C. Dickinson, J. B. Claridge, L. Jantsky and M. J. Rosseinsky, *Nat. Mater.*, 2008, **7**, 498–504.
- 15 M.-R. Li, X. Kuang, S. Y. Chong, Z. Xu, C. I. Thomas, H. Niu, J. B. Claridge and M. J. Rosseinsky, *Angew. Chem., Int. Ed.*, 2010, **49**, 2362–2366.
- 16 C. I. Thomas, X. Kuang, Z. Deng, H. Niu, J. B. Claridge and M. J. Rosseinsky, *Chem. Mater.*, 2010, **22**, 2510–2516.
- 17 P. R. Slater, J. E. Sansom and J. R. Tolchard, *Chem. Rec.*, 2004, **4**, 373–384.
- 18 H. S. Kim and H. I. Yoo, *Phys. Chem. Chem. Phys.*, 2010, **12**, 4704–4713.
- 19 A. L. Shaula, E. N. Naumovich, A. P. Viskup, V. V. Pankov, A. V. Kovalevsky and V. V. Kharton, *Solid State Ionics*, 2009, **180**, 812–816.
- 20 E. V. Tsipis, E. N. Naumovich, A. L. Shaula, M. V. Patrakeev, J. C. Waerenborgh and V. V. Kharton, *Solid State Ionics*, 2008, **179**, 57–60.
- 21 S. Abou-Warda, W. Pietzuch, G. Berghöfer, U. Kesper, W. Massa and D. Reinen, *J. Solid State Chem.*, 1998, **138**, 18–31.
- 22 S. J. Skinner and J. A. Kilner, *Ionics*, 1999, **5**, 171–174.
- 23 J. B. Goodenough and S. Ramasesha, *Mater. Res. Bull.*, 1982, **17**, 383–390.
- 24 N. Ye and J. L. Hertz, *Acta Mater.*, 2014, **63**, 123–129.
- 25 E. S. Raj, S. J. Skinner and J. A. Kilner, *Solid State Sci.*, 2004, **6**, 825–829.
- 26 H. S. Kim and H. I. Yoo, *Solid State Ionics*, 2013, **232**, 129–137.
- 27 J. Liu, S. Hull, I. Ahmed and S. J. Skinner, *Nucl. Instrum. Methods Phys. Res., Sect. B*, 2011, **269**, 539–543.
- 28 T. Ishihara, H. Matsuda, Y. Mizuhara and Y. Takita, *Solid State Ionics*, 1994, **70**, 234–238.
- 29 R. D. Shannon, *Acta Crystallogr., Sect. A: Cryst. Phys., Diffraction, Theor. Gen. Crystallogr.*, 1976, **32**, 751–767.
- 30 D. Ganguli, *J. Solid State Chem.*, 1979, **30**, 353–356.
- 31 A. Tarancón, T. Norby, G. Dezanneau, A. Morata, F. Peiró and J. Morante, *Electrochem. Solid-State Lett.*, 2004, **7**, A373–A375.
- 32 T. Ishihara, T. Akbay, H. Furutani and Y. Takita, *Solid State Ionics*, 1998, **113**, 585–591.
- 33 K. Huang and J. B. Goodenough, *J. Alloys Compd.*, 2000, **303**, 454–464.
- 34 D. Lybye, F. W. Poulsen and M. Mogensen, *Solid State Ionics*, 2000, **128**, 91–103.
- 35 I. Kosacki, V. Petrovsky and H. U. Anderson, *J. Electroceram.*, 2000, **4**, 243–249.
- 36 I. Kosacki and H. Tuller, *Solid State Ionics*, 1995, **80**, 223–229.
- 37 J. Y. Park and G. M. Choi, *Solid State Ionics*, 2002, **154**, 535–540.
- 38 S. Hull, *Rep. Prog. Phys.*, 2004, **67**, 1233–1314.
- 39 R. Baker, B. Gharbage and F. Marques, *J. Eur. Ceram. Soc.*, 1998, **18**, 105–112.
- 40 K. Huang, R. S. Tichy and J. B. Goodenough, *J. Am. Ceram. Soc.*, 1998, **81**, 2565–2575.
- 41 N. Kitamura, N. Hamao, S. C. Vogel and Y. Idemoto, *Electrochemistry*, 2013, **81**, 448–453.
- 42 H. Tuller, *Nonstoichiometric Oxides*, 1981, 271–335.
- 43 M. Burriel, M. Casas-Cabanas, J. Zapata, H. Tan, J. Verbeeck, C. Solís, J. Roqueta, S. J. Skinner, J. A. Kilner, G. Van Tendeloo and J. Santiso, *Chem. Mater.*, 2010, **22**, 5512–5520.
- 44 S. Y. Jeon, M. B. Choi, J. H. Hwang, E. D. Wachsman and S. J. Song, *J. Electrochem. Soc.*, 2011, **158**, B476–B480.

